

Supporting Information for
**Dual-Size Silicon Nanocrystal-Embedded SiO_x Nanocomposite
as a High-Capacity Lithium Storage**

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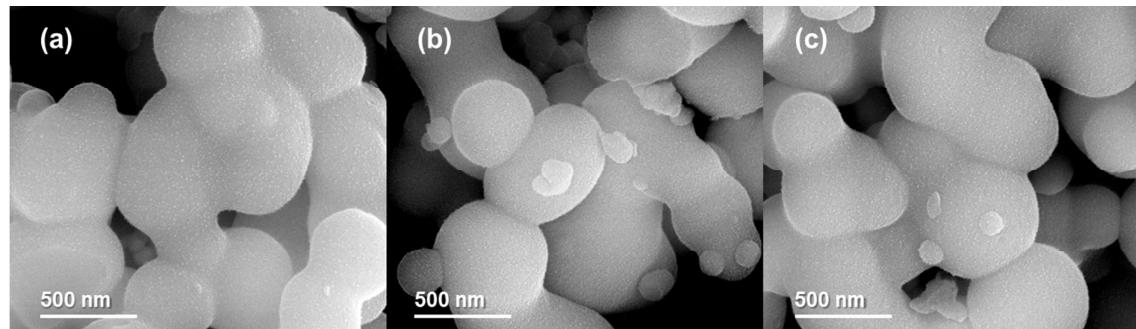


Figure S1. FESEM images of dual-sized Si nanocrystals embedded Si/SiO_x nanocomposites; (a) D-Si/SiO_x-1, (b) D-Si/SiO_x-2 and (c) D-Si/SiO_x-4.

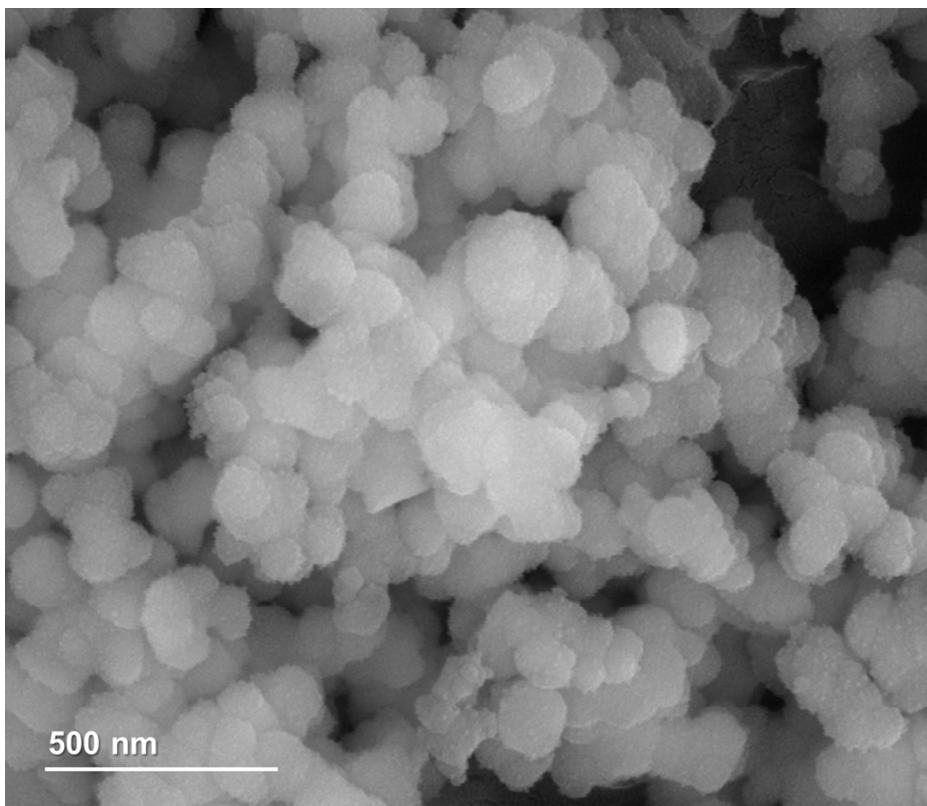


Figure S2. FESEM image of Si/SiO_x nanocomposite without Si-NP.

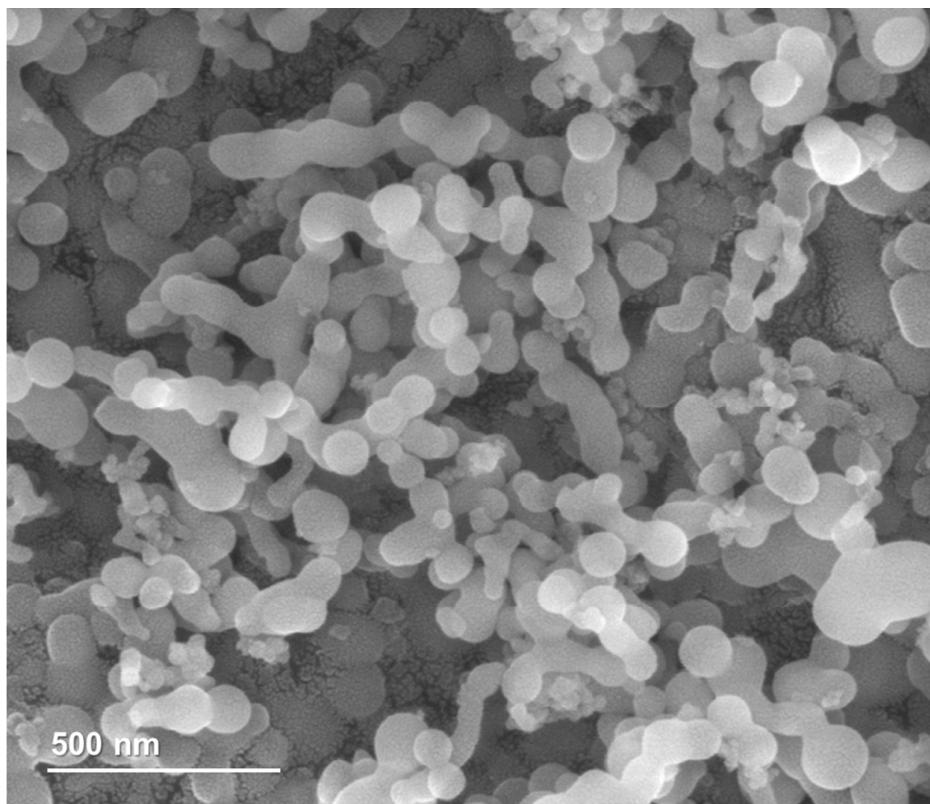


Figure S3. FESEM image of commercial Si nanoparticles (Si-NP).

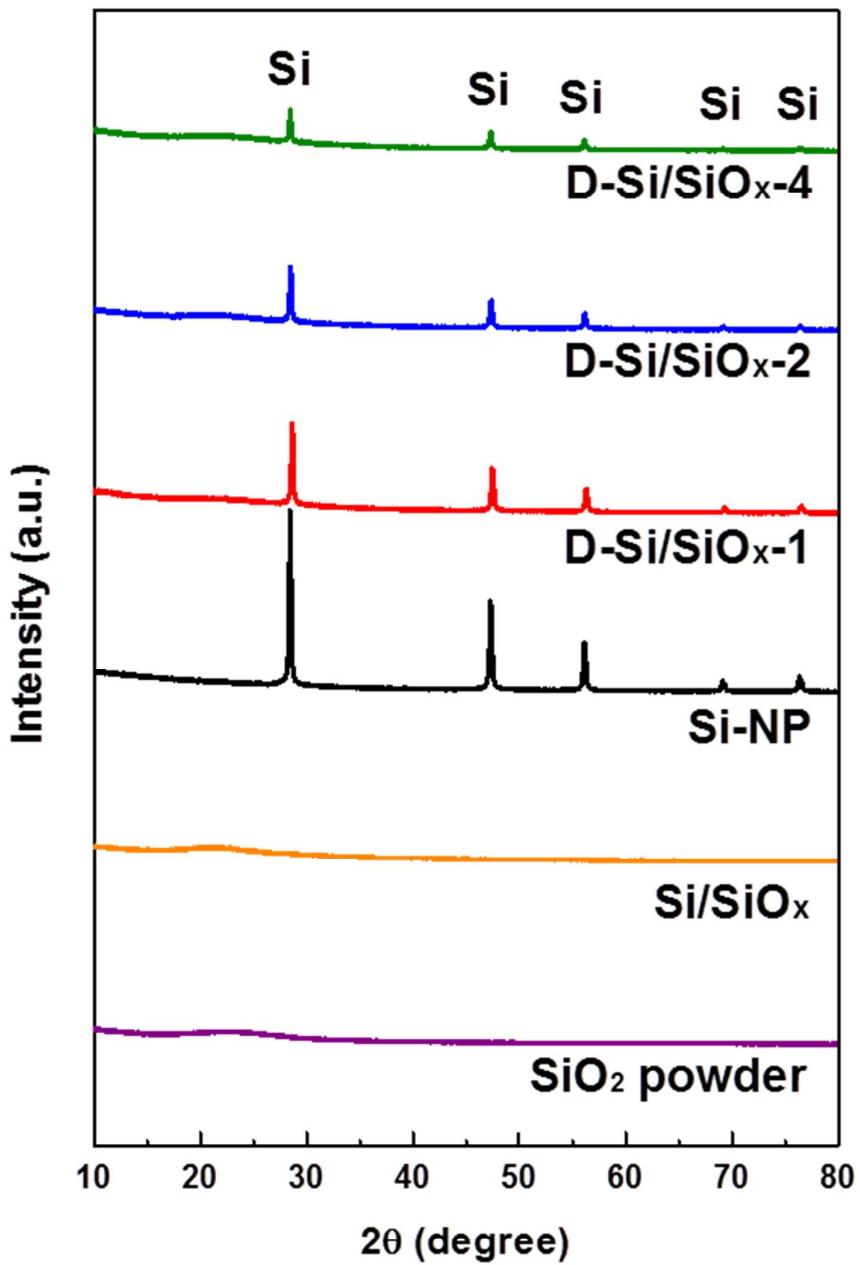


Figure S4. X-ray diffraction (XRD) patterns of D-Si/SiO_x-1, D-Si/SiO_x-2, D-Si/SiO_x-4 with those of Si-NP, Si/SiO_x and SiO₂ powder references.

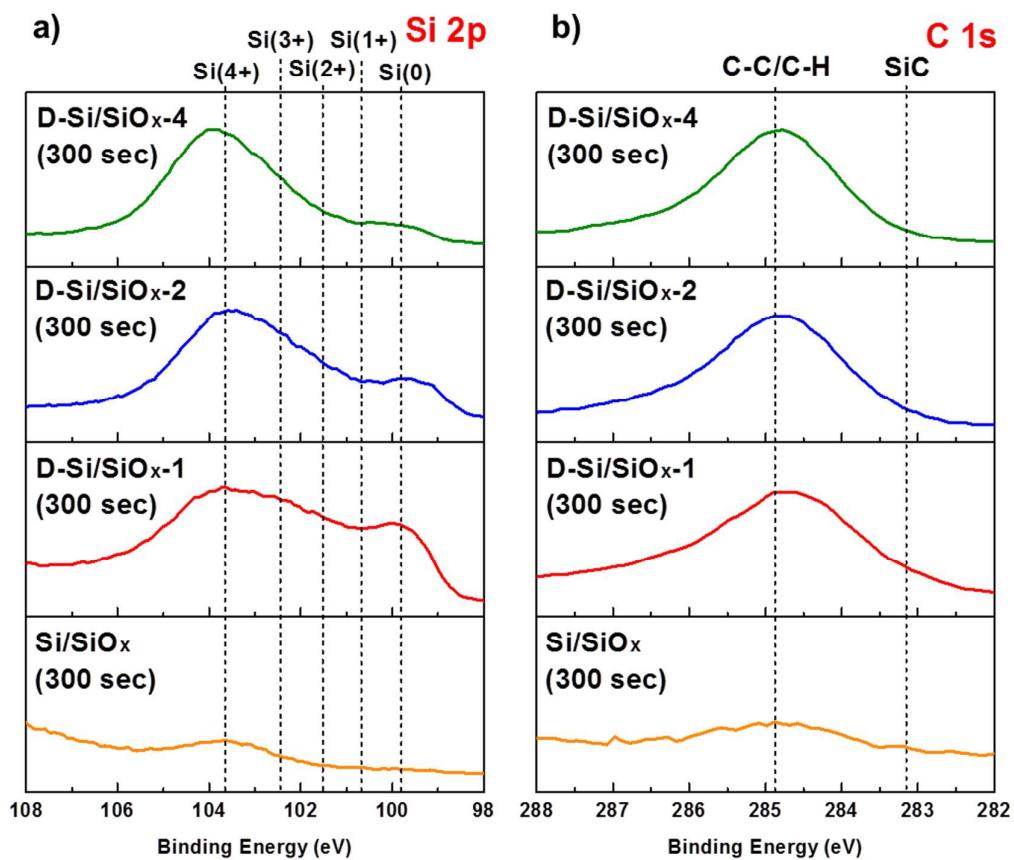


Figure S5. (a) Si 2p and (b) C 1s XPS spectra collected from various D-Si/SiO_x composites (D-Si/SiO_x-1, D-Si/SiO_x-2, D-Si/SiO_x-4) with the Si/SiO_x composite after Ar⁺ sputtering for 300 seconds.

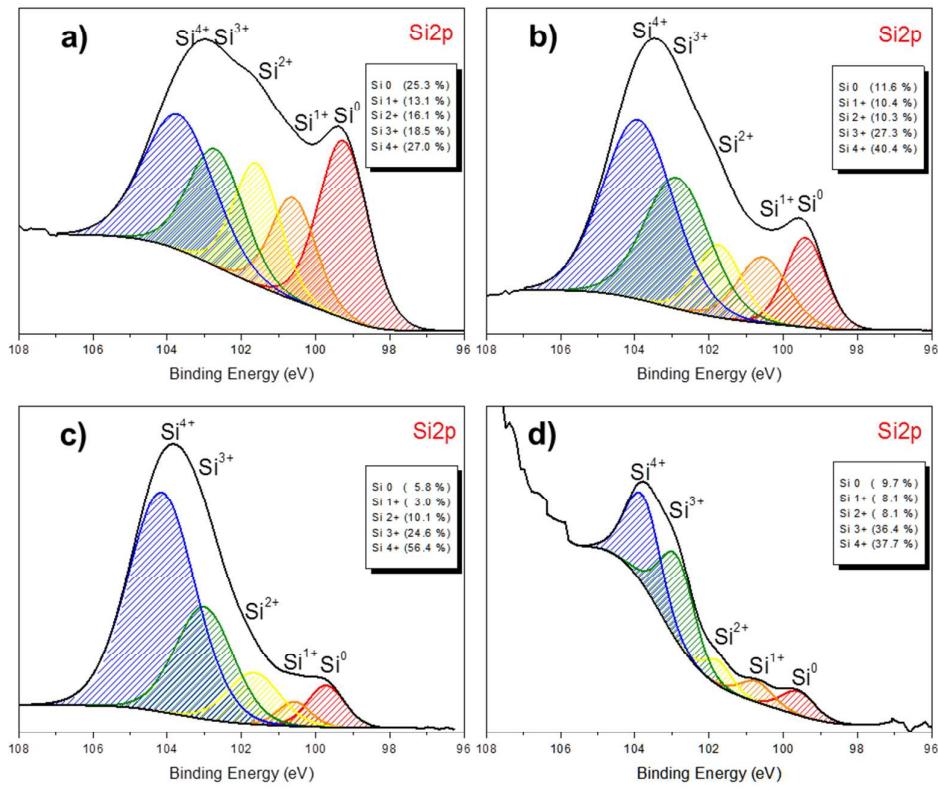


Figure S6. XPS Si 2p spectra of various D-Si/SiO_x with a Si/SiO_x composites after deconvolution with C 1s excitation at 284.8 eV; (a) D-Si/SiO_x-1, (b) D-Si/SiO_x-2, (c) D-Si/SiO_x-4, (d) the Si/SiO_x composite after Ar⁺ sputtering for 300 seconds.

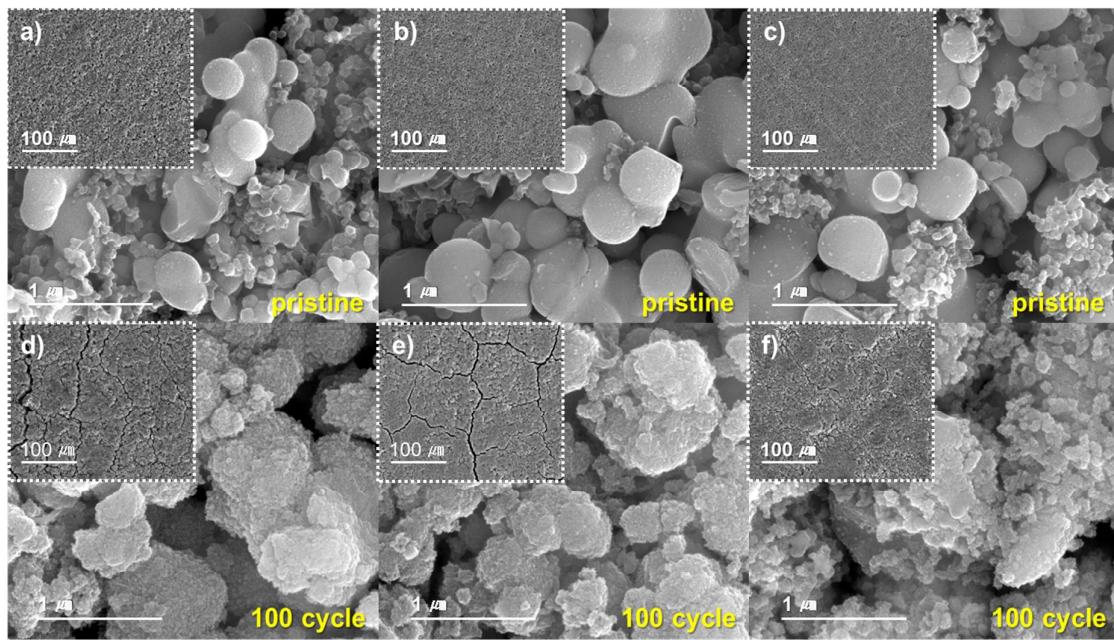


Figure S7. Top-view FESEM images of D-Si/SiO_x composite electrodes at different cycles; pristine and after 100 cycles electrode (a, d) D-Si/SiO_x-1 (b, e) D-Si/SiO_x-2 (c, f) D-Si/SiO_x-4. Insets show corresponding lower-magnification top-view FESEM images of the samples.

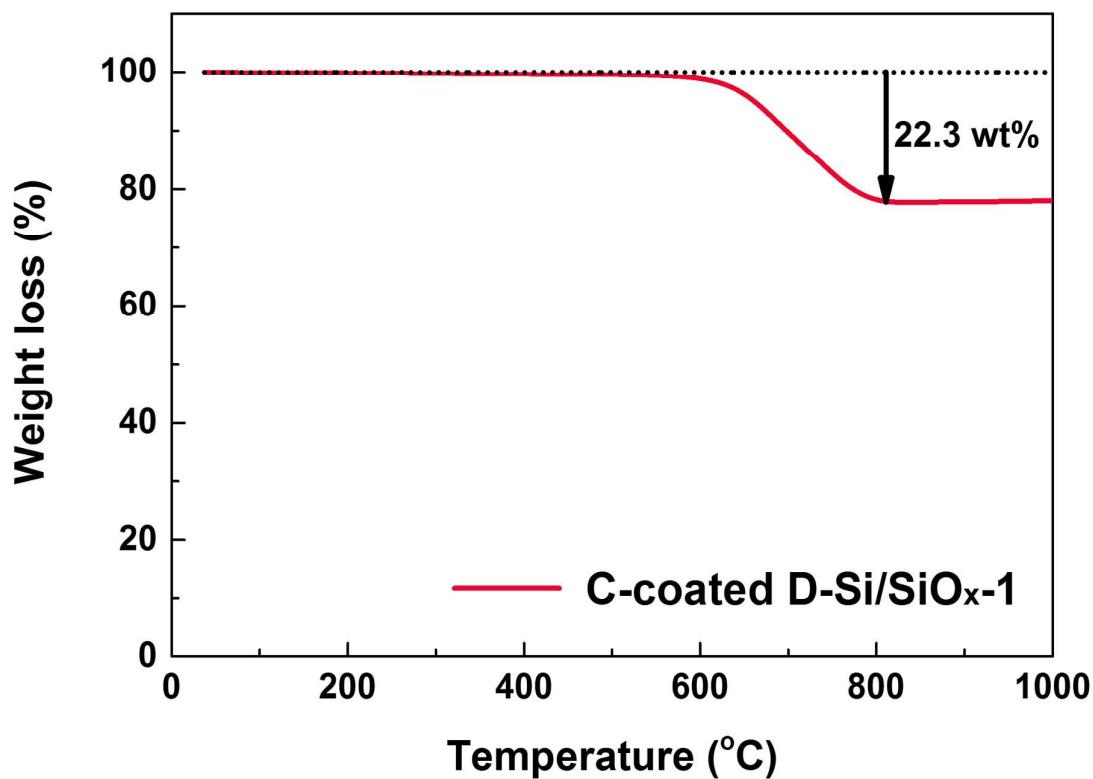


Figure S8. TGA curve of C-coated D-Si/SiO_x-1 nanocomposite after heat treatment at 1000 °C with 30 wt% of coal-tar pitch.